

科目：電子學

適用：電機系

編號：351

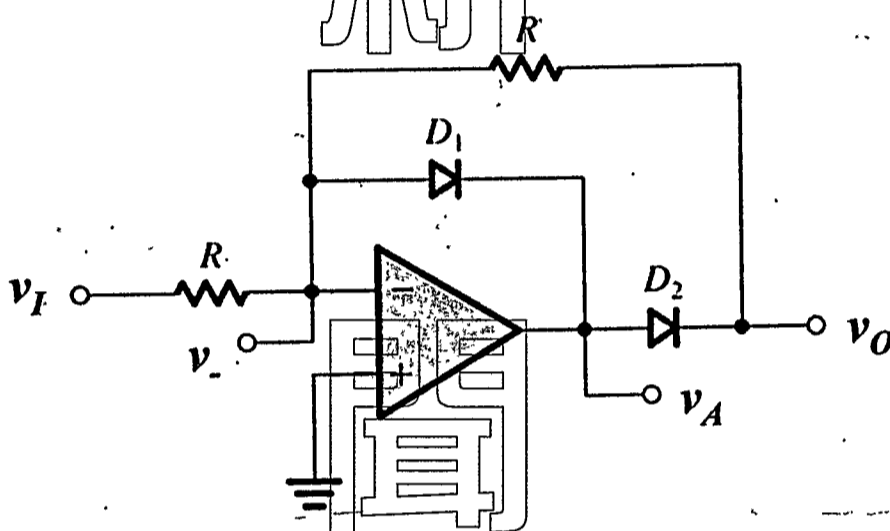
考生注意：

1. 依次序作答，只要標明題號，不必抄題。
2. 答案必須寫在答案卷上，否則不予計分。
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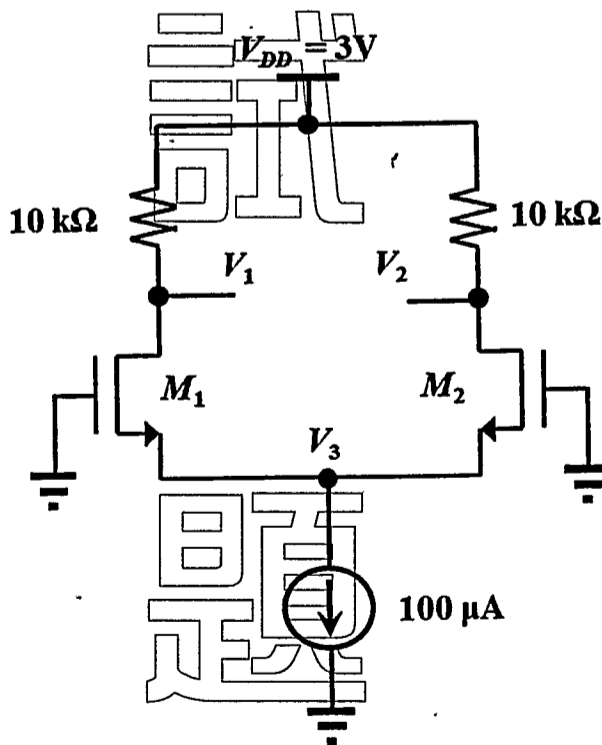
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1. Find the resistivity of (a) intrinsic silicon, and (b)  $n$ -type silicon with  $N_D = 10^{16}/\text{cm}^3$ . Use  $n_i = 1.5 \times 10^{10}/\text{cm}^3$ , and assume that for intrinsic silicon  $\mu_n = 1200 \text{ cm}^2/\text{V}\cdot\text{s}$  and  $\mu_p = 400 \text{ cm}^2/\text{V}\cdot\text{s}$ . Resistivity  $\rho = \frac{1}{q(p\mu_p + n\mu_n)}$ , where  $q = 1.6 \times 10^{-19}$ . [10%]

2. The op amp in the circuit below is ideal with output saturation levels of  $\pm 10 \text{ V}$ . The diodes exhibit a constant 0.7-V drop when conducting. Find  $v_-$ ,  $v_A$ , and  $v_o$  for: (a)  $v_I = +1 \text{ V}$ , (b)  $v_I = +3 \text{ V}$ , (c)  $v_I = -3 \text{ V}$ . [15%]



3. For the circuit shown below, transistors  $M_1$  and  $M_2$  have  $V_t = 0.5 \text{ V}$ , and the process transconductance parameter  $k'_n = 100 \mu\text{A}/\text{V}^2$ . Find  $V_1$ ,  $V_2$ , and  $V_3$  for each of the following cases: (a)  $(W/L)_1 = (W/L)_2 = 10$ , and (b)  $(W/L)_1 = 2 \cdot (W/L)_2 = 10$  [20%]



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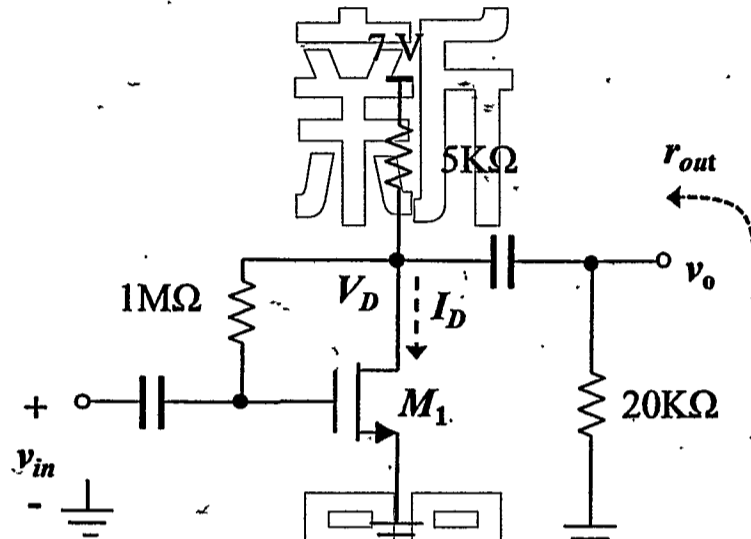
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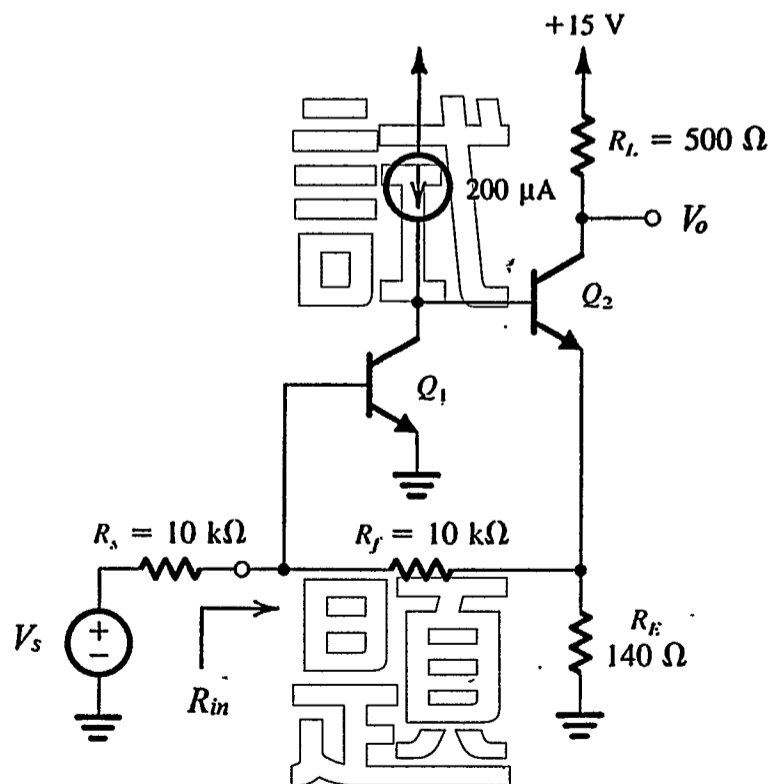
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4. Assume the capacitors in the circuit below to be sufficiently large so as to act as short circuit at the signal frequencies of interest.  $M_1$  has  $V_t = 1\text{V}$ ,  $k'_n(W/L) = 0.4\text{mA/V}^2$ , and  $V_A = 40\text{V}$ . Find (a) the dc value of  $V_D$  and  $I_D$ . (b) Draw its small-signal equivalent circuit. (c) Find the small signal voltage gain  $A_v = v_o/v_{in}$  and output resistance  $r_{out}$ . [15%]



5. For the feedback amplifier circuit shown below, assuming that  $V_s$  has a zero dc component, find the dc voltages at all nodes and the dc emitter currents of  $Q_1$  and  $Q_2$ . Let the BJTs have  $\beta = 100$ . Use feedback analysis to find  $V_o/V_s$  and  $R_{in}$ . Let  $V_{BE} = 0.7\text{V}$ . [20%]



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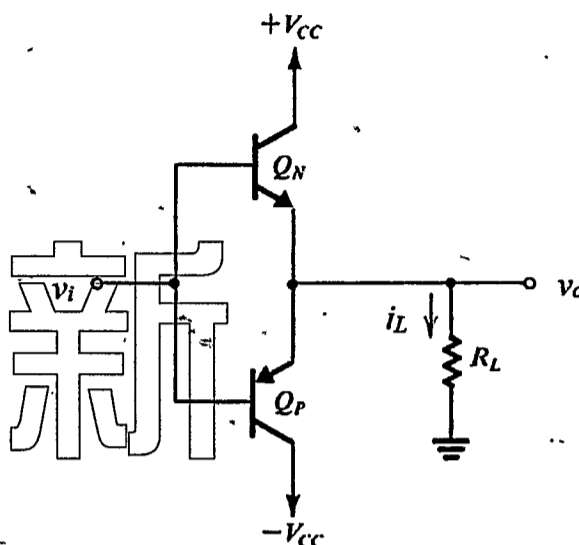
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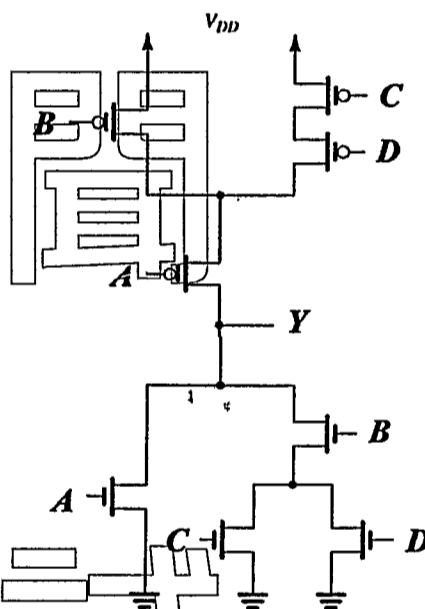
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6. For the class B output stage shown below, show that its maximum power conversion efficiency is 78.5%. [10%]



7. For the CMOS logic circuit shown below,  $A$ ,  $B$ ,  $C$  and  $D$  are digital inputs, what is the logic function of  $Y$ ? [5%]



8. For the instrument amplifier shown below, assume all op amps are ideal.  $v_d = v_2 - v_1$ , find the voltage gain  $A_o = v_o/v_d$ . [5%]

